## features

- Output Current: 1.1A
- Dropout Voltage: 310 mV
- Low Noise: $40 \mu \mathrm{~V}_{\text {RMS }}$ ( 10 Hz to 100 kHz )
- 500^A Quiescent Current (Adjustable Version)
- Wide Input Voltage Range: 1.8 V to 20 V
- No Protection Diodes Needed
- Controlled Quiescent Current in Dropout
- Adjustable Output from 1.20V to 19.5V
- Fixed Output Voltages: 1.5V, 1.8V, 2.5V, 3.3V
- < 1 $\mu \mathrm{A}$ Quiescent Current in Shutdown
- Stable with $10 \mu \mathrm{~F}$ Output Capacitor
- Stable with Ceramic, Tantalum or Aluminum Electrolytic Capacitors
- Reverse Battery Protection
- No Reverse Current
- Current Limit with Foldback Protection
- Thermal Limiting
- 5-Lead TO-220, DD-PAK, Thermally Enhanced 8-Lead MSOP and 8-Lead $3 \mathrm{~mm} \times 3 \mathrm{~mm}$ DFN Packages


## APPLICATIONS

- Logic Power Supplies
- Post Regulator for Switching Supplies
- Low Noise Instrumentation


## DESCRIPTION

The LT® ${ }^{\circledR} 1965$ series are low noise, low dropout linear regulators. The devices supply 1.1A of output current with a 310 mV typical dropout voltage. Operating quiescent current is $500 \mu \mathrm{~A}$ for the adjustable version, reducing to $<1 \mu \mathrm{~A}$ in shutdown. Quiescent current is well controlled; it does not rise in dropout as with many other regulators. The LT1965 regulators have very low output noise which makes them ideal for sensitive RF and DSP supply applications.
Output voltage ranges from 1.20 V to 19.5 V . The LT1965 regulators are stable with output capacitors as low as $10 \mu \mathrm{~F}$. Internal protection circuitry includes reverse battery protection, current limiting with foldback, thermal limiting and reverse current protection. The LT1965 series are available in fixed output voltages of $1.5 \mathrm{~V}, 1.8 \mathrm{~V}, 2.5 \mathrm{~V}, 3.3 \mathrm{~V}$, and as an adjustable device with a 1.20 V reference voltage. The package offerings include the 5 -lead T0-220, 5 -lead DD-PAK as well as the thermally enhanced 8-lead MSOP and low-profile ( 0.75 mm ) 8 -lead $3 \mathrm{~mm} \times 3 \mathrm{~mm}$ DFN.

[^0] All other trademarks are the property of their respective owners.

## TYPICAL APPLICATION



Dropout Voltage


## LT1965 Series

## ABSOLUTE MAXIMUM RATIOGS

(Note 1)
IN Pin Voltage e.. ..... $\pm 22 \mathrm{~V}$
OUT Pin Voltage ..... $\pm 22 \mathrm{~V}$
Input to Output Differential Voltage (Note 2) ..... $\pm 22 \mathrm{~V}$
SENSE Pin Voltage ..... $\pm 22 \mathrm{~V}$
ADJ Pin Voltage ..... $\pm 9 \mathrm{~V}$
SHDN Pin Voltage ..... $\pm 22 \mathrm{~V}$

Output Short-Circuit Duration ......................... Indefinite Operating Junction Temperature Range (E, I Grade) (Notes 2, 13) $\qquad$ .$-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Storage Temperature Range.

$\qquad$
$-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
Lead Temperature (Soldering, 10 sec )
(Only for MSOP, T0-220, DD-PAK Packages).... $300^{\circ} \mathrm{C}$

## PIn CONFIGURATION



## ORDER INFORMATION

| LEAD FREE FINISH | TAPE AND REEL | PART MARKING* | PACKAGE DESCRIPTION | TEMPERATURE RANGE |
| :--- | :--- | :--- | :--- | :--- |
| LT1965EDD\#PBF | LT1965EDD\#TRPBF | LCXW | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IDD\#PBF | LT1965IDD\#TRPBF | LCXW | 8 -Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EDD-1.5\#PBF | LT1965EDD-1.5\#TRPBF | LDKW | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IDD-1.5\#PBF | LT1965IDD-1.5\#TRPBF | LDKW | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EDD-1.8\#PBF | LT1965EDD-1.8\#TRPBF | LDKY | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IDD-1.8\#PBF | LT1965IDD-1.8\#TRPBF | LDKY | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EDD-2.5\#PBF | LT1965EDD-2.5\#TRPBF | LDMB | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IDD-2.5\#PBF | LT1965IDD-2.5\#TRPBF | LDMB | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EDD-3.3\#PBF | LT1965EDD-3.3\#TRPBF | LDMD | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IDD-3.3\#PBF | LT1965IDD-3.3\#TRPBF | LDMD | 8-Lead $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |

## LT1965 Series

## ORDER InFORMATION

| LEAD FREE FINISH | TAPE AND REEL | PART MARKING* | PACKAGE DESCRIPTION | TEMPERATURE RANGE |
| :---: | :---: | :---: | :---: | :---: |
| LT1965EMS8E\#PBF | LT1965EMS8E\#TRPBF | LTCXX | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IMS8E\#PBF | LT1965IMS8E\#TRPBF | LTCXX | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EMS8E-1.5\#PBF | LT1965EMS8E-1.5\#TRPBF | LTDKX | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IMS8E-1.5\#PBF | LT1965IMS8E-1.5\#TRPBF | LTDKX | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EMS8E-1.8\#PBF | LT1965EMS8E-1.8\#TRPBF | LTDKZ | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IMS8E-1.8\#PBF | LT1965IMS8E-1.8\#TRPBF | LTDKZ | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EMS8E-2.5\#PBF | LT1965EMS8E-2.5\#TRPBF | LTDMC | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IMS8E-2.5\#PBF | LT1965IMS8E-2.5\#TRPBF | LTDMC | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EMS8E-3.3\#PBF | LT1965EMS8E-3.3\#TRPBF | LTDMF | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IMS8E-3.3\#PBF | LT1965IMS8E-3.3\#TRPBF | LTDMF | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EQ\#PBF | LT1965EQ\#TRPBF | LT1965Q | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IQ\#PBF | LT1965IQ\#TRPBF | LT1965Q | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EQ-1.5\#PBF | LT1965EQ-1.5\#TRPBF | LT1965Q-1.5 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IQ-1.5\#PBF | LT1965IQ-1.5\#TRPBF | LT1965Q-1.5 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EQ-1.8\#PBF | LT1965EQ-1.8\#TRPBF | LT1965Q-1.8 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IQ-1.8\#PBF | LT1965IQ-1.8\#TRPBF | LT1965Q-1.8 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EQ-2.5\#PBF | LT1965EQ-2.5\#TRPBF | LT1965Q-2.5 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IQ-2.5\#PBF | LT1965IQ-2.5\#TRPBF | LT1965Q-2.5 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965EQ-3.3\#PBF | LT1965EQ-3.3\#TRPBF | LT1965Q-3.3 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IQ-3.3\#PBF | LT1965IQ-3.3\#TRPBF | LT1965Q-3.3 | 5-Lead Plastic DD-PAK | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965ET\#PBF | LT1965ET\#TRPBF | LT1965T | 5-Lead Plastic T0-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IT\#PBF | LT1965IT\#TRPBF | LT1965T | 5-Lead Plastic T0-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965ET-1.5\#PBF | LT1965ET-1.5\#TRPBF | LT1965T-1.5 | 5-Lead Plastic T0-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IT-1.5\#PBF | LT1965IT-1.5\#TRPBF | LT1965T-1.5 | 5-Lead Plastic TO-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965ET-1.8\#PBF | LT1965ET-1.8\#TRPBF | LT1965T-1.8 | 5-Lead Plastic TO-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IT-1.8\#PBF | LT1965IT-1.8\#TRPBF | LT1965T-1.8 | 5-Lead Plastic TO-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965ET-2.5\#PBF | LT1965ET-2.5\#TRPBF | LT1965T-2.5 | 5-Lead Plastic TO-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IT-2.5\#PBF | LT1965IT-2.5\#TRPBF | LT1965T-2.5 | 5-Lead Plastic T0-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965ET-3.3\#PBF | LT1965ET-3.3\#TRPBF | LT1965T-3.3 | 5-Lead Plastic T0-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT1965IT-3.3\#PBF | LT1965IT-3.3\#TRPBF | LT1965T-3.3 | 5-Lead Plastic T0-220 | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |

Consult LTC Marketing for parts specified with wider operating temperature ranges. *Temperature grades are identified by a label on the shipping container.
Consult LTC Marketing for information on non-standard lead based finish parts.
For more information on lead free part marking, go to: http://www.linear.com/leadfree/
For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

## LT1965 Series

ELECTRICAL CHARACTERISTICS The • denotes the speciications which apply over the full operating temperature range, otherwise specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$. (Note 3)

| PARAMETER | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Minimum Input Voltage (Notes 4, 12) | $\begin{aligned} & l_{\text {LOAD }}=0.5 \mathrm{~A} \\ & \mathrm{l}_{\text {LOAD }}=1.1 \mathrm{~A} \end{aligned}$ | $\bullet$ |  | $\begin{gathered} 1.65 \\ 1.8 \end{gathered}$ | 2.3 | V |
| Regulated Output Voltage (Note 5) | $\begin{aligned} & \text { LT1965-1.5, } \mathrm{V}_{\text {IN }}=2.1 \mathrm{~V}, \mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA} \\ & \text { LT1965-1.5, } 2.5<\mathrm{V}_{\text {IN }}<20 \mathrm{~V}, 1 \mathrm{~mA}<\mathrm{I}_{\text {LOAD }}<1.1 \mathrm{~A} \end{aligned}$ | $\bullet$ | $\begin{aligned} & 1.477 \\ & 1.455 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & 1.523 \\ & 1.545 \end{aligned}$ | V |
|  | $\begin{aligned} & \text { LT1965-1.8, } \mathrm{V}_{\text {IN }}=2.3 \mathrm{~V}, \mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA} \\ & \text { LT1965-1.8, } 2.8<\mathrm{V}_{\text {IN }}<20 \mathrm{~V}, 1 \mathrm{~mA}<\mathrm{I}_{\text {LOAD }}<1.1 \mathrm{~A} \end{aligned}$ | $\bullet$ | $\begin{aligned} & 1.773 \\ & 1.746 \end{aligned}$ | $\begin{aligned} & 1.8 \\ & 1.8 \end{aligned}$ | $\begin{aligned} & 1.827 \\ & 1.854 \end{aligned}$ | V |
|  | $\begin{aligned} & \text { LT1965-2.5, } \mathrm{V}_{\text {IN }}=3 \mathrm{~V}_{\mathrm{I}} \mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA} \\ & \text { LT1965-2.5, } 3.5<\mathrm{V}_{\text {IN }}<20 \mathrm{~V}, 1 \mathrm{~mA}<\mathrm{I}_{\text {LOAD }}<1.1 \mathrm{~A} \end{aligned}$ | $\bullet$ | $\begin{aligned} & 2.462 \\ & 2.425 \end{aligned}$ | $\begin{aligned} & 2.5 \\ & 2.5 \end{aligned}$ | $\begin{aligned} & 2.538 \\ & 2.575 \end{aligned}$ | V |
|  | $\begin{aligned} & \text { LT1965-3.3, } \mathrm{V}_{\text {IN }}=3.8 \mathrm{~V}, \mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA} \\ & \text { LT1965-3.3, } 4.3<V_{\text {IN }}<20 \mathrm{~V}, 1 \mathrm{~mA}<\mathrm{I}_{\text {LOAD }}<1.1 \mathrm{~A} \end{aligned}$ | $\bullet$ | $\begin{aligned} & 3.25 \\ & 3.201 \end{aligned}$ | $\begin{aligned} & 3.3 \\ & 3.3 \end{aligned}$ | $\begin{aligned} & 3.35 \\ & 3.399 \end{aligned}$ | V |
| ADJ Pin Voltage (Notes 4, 5) | $\begin{aligned} & V_{I N}=2.1 \mathrm{~V}, \mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA} \\ & 2.3 \mathrm{~V}<\mathrm{V}_{\text {IN }}<20 \mathrm{~V}, 1 \mathrm{~mA}<\mathrm{I}_{\text {LOAD }}<1.1 \mathrm{~A} \end{aligned}$ | $\bullet$ | $\begin{aligned} & 1.182 \\ & 1.164 \end{aligned}$ | $\begin{aligned} & 1.2 \\ & 1.2 \end{aligned}$ | $\begin{aligned} & 1.218 \\ & 1.236 \end{aligned}$ | V |
| Line Regulation | LT1965-1.5, $\Delta \mathrm{V}_{\text {IN }}=2.1 \mathrm{~V}$ to 20V, $\mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA}$ <br> LT1965-1.8, $\Delta \mathrm{V}_{\text {IN }}=2.3 \mathrm{~V}$ to 20V, $\mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA}$ <br> LT1965-2.5, $\Delta \mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA}$ <br> LT1965-3.3, $\Delta \mathrm{V}_{\text {IN }}=3.8 \mathrm{~V}$ to 20V, $\mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA}$ <br> LT1965, $\quad \Delta \mathrm{V}_{\text {IN }}=2.1 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{I}_{\text {LOAD }}=1 \mathrm{~mA}$ (Note 4) | $\begin{aligned} & \bullet \\ & \bullet \\ & \bullet \\ & \bullet \end{aligned}$ |  | $\begin{gathered} 3.5 \\ 4 \\ 4.5 \\ 5.5 \\ 3 \end{gathered}$ | $\begin{gathered} 9 \\ 10 \\ 11.5 \\ 16 \\ 8 \end{gathered}$ | $m V$ $m V$ $m V$ $m V$ $m V$ |
| Load Regulation | LT1965-1.5, $\mathrm{V}_{\text {IN }}=2.5 \mathrm{~V}, \Delta \mathrm{~L}_{\text {LOAD }}=1 \mathrm{~mA}$ to 1.1 A LT1965-1.5, $\mathrm{V}_{\text {IN }}=2.5 \mathrm{~V},\left.\Delta\right\|_{\text {LOAD }}=1 \mathrm{~mA}$ to 1.1 A | $\bullet$ |  | 5.25 | $\begin{aligned} & 10 \\ & 20 \end{aligned}$ | mV mV |
|  | $\begin{aligned} & \mathrm{LT1965-1.8,} \mathrm{~V}_{\text {IN }}=2.8 \mathrm{~V}, \Delta \mathrm{~L}_{\text {LOAD }}=1 \mathrm{~mA} \text { to } 1.1 \mathrm{~A} \\ & \mathrm{LT} 1965-1.8, \mathrm{~V}_{\text {IN }}=2.8 \mathrm{~V},\left.\Delta\right\|_{\text {LOAD }}=1 \mathrm{~mA} \text { to } 1.1 \mathrm{~A} \end{aligned}$ | $\bullet$ |  | 6.25 | $\begin{aligned} & 12 \\ & 24 \end{aligned}$ | mV mV |
|  | LT1965-2.5, $\mathrm{V}_{\text {IN }}=3.5 \mathrm{~V}, \Delta \mathrm{~L}_{\text {LOAD }}=1 \mathrm{~mA}$ to 1.1 A <br> LT1965-2.5, $\mathrm{V}_{\text {IN }}=3.5 \mathrm{~V}, \Delta \mathrm{~L}_{\text {LOAD }}=1 \mathrm{~mA}$ to 1.1 A | $\bullet$ |  | 8.75 | $\begin{gathered} 16.5 \\ 33 \end{gathered}$ | mV mV |
|  | LT1965-3.3, $\mathrm{V}_{\text {IN }}=4.3 \mathrm{~V}, \Delta_{\text {LOAD }}=1 \mathrm{~mA}$ to 1.1 A <br> LT1965-3.3, $\mathrm{V}_{\text {IN }}=4.3 \mathrm{~V}, \mathrm{\Delta}_{\mathrm{LOAD}}=1 \mathrm{~mA}$ to 1.1 A | $\bullet$ |  | 11.5 | $\begin{aligned} & 22 \\ & 44 \end{aligned}$ | mV mV |
|  | LT1965, $\quad \mathrm{V}_{\text {IN }}=2.3 \mathrm{~V}, \Delta \mathrm{~L}_{\text {LOAD }}=1 \mathrm{~mA}$ to 1.1 A (Note 4) <br> LT1965, $\quad V_{\text {IN }}=2.3 \mathrm{~V}, \Delta \mathrm{~L}_{\text {LOAD }}=1 \mathrm{~mA}$ to 1.1 A (Note 4) | $\bullet$ |  | 4.25 | $\begin{gathered} \hline 8 \\ 16 \end{gathered}$ | mV mV |
| Dropout Voltage $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {OUT (NOMINAL }}$ (Notes 6, 7, 12) | $\begin{aligned} & l_{\text {LOAD }}=1 \mathrm{~mA} \\ & \mathrm{l}_{\mathrm{LOAD}}=1 \mathrm{~mA} \end{aligned}$ | $\bullet$ |  | 0.055 | $\begin{aligned} & 0.08 \\ & 0.14 \end{aligned}$ | V |
|  | $\begin{aligned} & \mathrm{I}_{\mathrm{LOAD}}=100 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{LOAD}}=100 \mathrm{~mA} \end{aligned}$ | $\bullet$ |  | 0.12 | $\begin{gathered} 0.175 \\ 0.28 \end{gathered}$ | V |
|  | $\begin{aligned} & \mathrm{I}_{\mathrm{LOAD}}=500 \mathrm{~mA} \\ & \mathrm{~L}_{\text {LOAD }}=500 \mathrm{~mA} \end{aligned}$ | $\bullet$ |  | 0.21 | $\begin{aligned} & \hline 0.25 \\ & 0.36 \end{aligned}$ | V |
|  | $\begin{aligned} & l_{\text {LOAD }}=1.1 \mathrm{~A} \\ & \mathrm{l}_{\mathrm{LOAD}}=1.1 \mathrm{~A} \\ & \hline \end{aligned}$ | $\bullet$ |  | 0.31 | $\begin{aligned} & 0.36 \\ & 0.49 \end{aligned}$ | V |
| GND Pin Current <br> $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {OUT(NOMINAL }}+1 \mathrm{~V}$ <br> (Notes 6, 8) | $\begin{aligned} & l_{\text {LOAD }}=0 \mathrm{~mA} \\ & l_{\text {LOAD }}=1 \mathrm{~mA} \\ & l_{\text {LOAD }}=100 \mathrm{~mA} \\ & l_{\text {LOAD }}=500 \mathrm{~mA} \\ & I_{\text {LOAD }}=1.1 \mathrm{~A} \end{aligned}$ | $\stackrel{\bullet}{\bullet} \stackrel{\bullet}{\bullet}$ |  | $\begin{aligned} & 0.5 \\ & 0.6 \\ & 2.2 \\ & 8.2 \\ & 21 \end{aligned}$ | $\begin{aligned} & 1.1 \\ & 1.5 \\ & 5.5 \\ & 20 \\ & 40 \\ & \hline \end{aligned}$ | mA mA mA mA mA |
| Output Voltage Noise | $\mathrm{C}_{\text {OUT }}=10 \mu \mathrm{~F}, \mathrm{I}_{\text {LOAD }}=1.1 \mathrm{~A}, \mathrm{BW}=10 \mathrm{~Hz}$ to 100 kHz |  |  | 40 |  | $\mu V_{\text {RMS }}$ |
| ADJ Pin Bias Current (Notes 4, 9) |  |  |  | 1.3 | 4.5 | $\mu \mathrm{A}$ |
| Shutdown Threshold | $\begin{aligned} & V_{\text {OUT }}=0 \mathrm{ff} \text { to } 0 \mathrm{n} \\ & \mathrm{~V}_{\text {OUT }}=0 \mathrm{n} \text { to } 0 \mathrm{ff} \end{aligned}$ | $\bullet$ | 0.2 | $\begin{aligned} & 0.85 \\ & 0.45 \end{aligned}$ | 2 | V |
| $\overline{\overline{\text { SHDN }} \text { Pin Current (Note 10) }}$ | $\begin{aligned} & V_{\overline{S H D N}}=0 \mathrm{~V} \\ & V_{\overline{S H D N}}=20 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 0.01 \\ 5.5 \end{gathered}$ | $\begin{gathered} 1 \\ 10 \end{gathered}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| Quiescent Current in Shutdown | $\mathrm{V}_{\text {IN }}=6 \mathrm{~V}, \mathrm{~V}_{\text {SHDN }}=0 \mathrm{~V}$ |  |  | 0.01 | 1 | $\mu \mathrm{A}$ |
| Ripple Rejection | $\begin{aligned} & \mathrm{V}_{\text {IN }}-\mathrm{V}_{\text {OUT }}=1.5 \mathrm{~V}(\mathrm{AVG}), \mathrm{V}_{\text {RIPPLE }}=0.5 \mathrm{~V}_{\text {P-P, }} \\ & \mathrm{f}_{\text {RIPPLE }}=120 \mathrm{~Hz}, \mathrm{I}_{\text {LOAD }}=0.75 \mathrm{~A} \end{aligned}$ |  | 57 | 75 |  | dB |

ELECTRICAL CHARACTERISTICS The odenotes she sperifiationos wilich ppply ver the tull operating
temperature range, otherwise specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$. (Note 3)

| PARAMETER | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Current Limit | $\begin{aligned} & V_{\text {IN }}=7 V, V_{\text {OUT }}=0 \\ & V_{\text {IN }}=V_{\text {OUT(NOMINAL }}+1 V, \Delta V_{\text {OUT }}=-0.1 \mathrm{~V}(\text { Note } 6) \end{aligned}$ | $\bullet$ | 1.2 | 2.4 |  | A |
| Input Reverse Leakage Current | $\mathrm{V}_{\text {IN }}=-20 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0$ |  |  |  | 1 | mA |
| Reverse Output Current (Note 11) | LT1965-1.5, $\mathrm{V}_{\text {OUT }}=1.5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0$ <br> LT1965-1.8, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0$ <br> LT1965-2.5, $\mathrm{V}_{\text {OUT }}=2.5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0$ <br> LT1965-3.3, $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0$ <br> LT1965 (Note 4), $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0$ |  |  | $\begin{aligned} & \hline 275 \\ & 275 \\ & 275 \\ & 275 \\ & 175 \end{aligned}$ | $\begin{aligned} & 525 \\ & 525 \\ & 525 \\ & 525 \\ & 400 \end{aligned}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ |

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.
Note 2: Absolute maximum input to output differential voltage is not achievable with all combinations of rated IN pin and OUT pin voltages. With the IN pin at 22 V , the OUT pin may not be pulled below OV. The total measured voltage from IN to OUT must not exceed $\pm 22 \mathrm{~V}$.
Note 3: The LT1965 regulators are tested and specified under pulse load conditions such that $T_{J} \cong T_{A}$. The LT1965E regulators are $100 \%$ tested at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$. Performance at $-40^{\circ} \mathrm{C}$ and $125^{\circ} \mathrm{C}$ is assured by design, characterization, and correlation with statistical process controls. The LT1965I regulators are guaranteed over the full $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ operating junction temperature range.
Note 4: The LT1965 adjustable version is tested and specified for these conditions with the ADJ connected to the OUT pin.
Note 5: Maximum junction temperature limits operating conditions. The regulated output voltage specification does not apply for all possible combinations of input voltage and output current. Limit the output current range if operating at the maximum input voltage. Limit the input-to-output voltage differential if operating at the maximum output current.
Note 6: To satisfy minimum input voltage requirements, the LT1965 adjustable version is tested and specified for these conditions with an external resistor divider (bottom 4.02k, top 4.32k) for an output voltage of
2.5 V . The external resistor divider adds $300 \mu \mathrm{~A}$ of output DC load current. This external current is not factored into GND pin current.
Note 7: Dropout voltage is the minimum input-to-output voltage differential needed to maintain regulation at a specified output current. In dropout, the output voltage equals: $\left(\mathrm{V}_{\text {IN }}-\mathrm{V}_{\text {DROPOUT }}\right)$
Note 8: GND pin current is tested with $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {OUT(NOMINAL) }}+1 \mathrm{~V}$ and a current source load. GND pin current increases slightly in dropout. For the fixed output versions, an internal resistor divider will typically add $100 \mu A$ to the GND pin current. See GND pin current curves in the Typical Performance Characteristics section.
Note 9: ADJ pin bias current flows into the ADJ pin.
Note 10: $\overline{\text { SHDN }}$ pin current flows into the $\overline{\text { SHDN }}$ pin.
Note 11: Reverse output current is tested with the IN pin grounded and the OUT pin forced to the rated output voltage. This current flows into the OUT pin and out of the GND pin.
Note 12: For the LT1965, LT1965-1.5 and LT1965-1.8, the minimum input voltage specification limits the dropout voltage under some output voltage/load conditions.
Note 13: This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed $125^{\circ} \mathrm{C}$ when overtemperature is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

## LT1965 Series

## TYPICAL PERFORMANCE CHARACTERISTICS



Quiescent Current


Guaranteed Dropout Voltage


LT1965-1.5 Output Voltage


1965 G05


1965603

LT1965-1.8 Output Voltage


1965 G06

LT1965-2.5 Output Voltage


LT1965-3.3 Output Voltage


LT1965 ADJ Pin Voltage


## TYPICAL PERFORMANCE CHARACTERISTICS



LT1965-3.3 Quiescent Current


LT1965-1.5 GND Pin Current (Heavy Load)


LT1965-1.8 Quiescent Current


965 G11

## LT1965 Quiescent Current



LT1965-1.8 GND Pin Current (Light Load)


LT1965-2.5 Quiescent Current


LT1965-1.5 GND Pin Current (Light Load)


LT1965-1.8 GND Pin Current (Heavy Load)


## LT1965 Series

## TYPICAL PERFORMANCE CHARACTERISTICS



LT1965-3.3 GND Pin Current (Heavy Load)


1965 G22


1965 G20

## LT1965 GND Pin Current

 (Light Load)

LT1965-3.3 GND Pin Current (Light Load)


LT1965 GND Pin Current (Heavy Load)


GND Pin Current vs I LOAD

$\overline{\text { SHDN }}$ Pin Threshold


TYPICAL PERFORMANCE CHARACTERISTICS


Reverse Output Current


Ripple Rejection vs Frequency


1965 G33
1965 G34

## LT1965 Series

## TYPICAL PERFORMANCE CHARACTERISTICS



LT1965-3.3 Transient Response



1965 G41

LT1965-2.5 SHDN Transient Response

$\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$
Cout $=10 \mu$ F CERAMIC
$R_{L}=2.5 \mathrm{k}, \mathrm{I}_{\mathrm{L}}=1 \mathrm{~mA}$ FOR $\mathrm{V}_{\text {OUT }}=2.5 \mathrm{~V}$

## PIn FUnCTIOnS (dFN/MSop/DD-Рак/TO-220)

OUT (Pins 1, 2 / 1, 2 / 4 / 4): Output. This pin supplies power to the load. Use a minimum output capacitor of $10 \mu \mathrm{~F}$ to prevent oscillations. Large load transient applications require larger output capacitors to limit peak voltage transients. See the Applications Information section for more information on output capacitance and reverse output characteristics.

SENSE (Pin 3 / 3 / 5 / 5): Sense. For fixed voltage versions of the LT1965 (LT1965-1.5/LT1965-1.8/LT1965-2.5/ LT1965-3.3), the SENSE pin is the input to the error amplifier. Optimum regulation is obtained when the SENSE pin is connected to the OUT pin of the regulator. In critical applications, small voltage drops are caused by the resistance $\left(R_{p}\right)$ of PCB traces between the regulator and the load. These drops may be eliminated by connecting the SENSE pin to the output at the load as shown in Figure 1 (Kelvin Sense Connection). Note that the voltage drop across the external PCB traces will add to the dropout voltage of the regulator. The SENSE pin bias current is $100 \mu \mathrm{~A}$ at the nominal rated output voltage. The SENSE pin can be pulled below ground (as in a dual supply system where the regulator load is returned to a negative supply) while still allowing the device to start and operate.


Figure 1. Kelvin Sense Connection

ADJ (Pin $3 / 3 / 5 / 5)$ : Adjust. This pin is the input to the error amplifier. It has a typical bias current of $1.3 \mu \mathrm{~A}$ that flows into the pin. The ADJ pin voltage is 1.20 V referenced to ground.

GND (Pins 4, 5 / 4, 5 / 3 / 3): Ground. For the adjustable LT1965, connect the bottom of the resistor divider, setting output voltage, directly to GND for optimum regulation.
$\overline{\text { SHDN }}$ (Pin 6 / 6 / 1 / 1): Shutdown. Pulling the $\overline{\text { SHDN }}$ pin low puts the LT1965 into a low power state and turns the output off. Drive the $\overline{\text { SHDN }}$ pin with either logic or an open collector/drain with a pull-up resistor. The resistor supplies the pull-up current to the open collector/drain logic, normally several microamperes and the SHDN pin current, typically less than $5.5 \mu \mathrm{~A}$. If unused, connect the $\overline{S H D N}$ pin to $\mathrm{V}_{\mathrm{IN}}$. The $\overline{\text { SHDN }}$ pin cannot be driven below GND unless it is tied to the IN pin. If the SHDN pin is driven below GND while IN is powered, the output will turn on. SHDN pin logic cannot be referenced to a negative supply rail.
IN (Pins 7, 8/7, 8/2 / 2): Input. This pin supplies power to the device. The LT1965 requires a bypass capacitor at IN if located more than six inches from the main input filter capacitor. Include a bypass capacitor in battery-powered circuits as a battery's output impedance generally rises with frequency. A bypass capacitor in the range of $1 \mu \mathrm{~F}$ to $10 \mu \mathrm{~F}$ suffices. The LT1965's design withstands reverse voltages on the IN pin with respect to ground and the OUT pin. In the case of a reversed input, which occurs if a battery is plugged in backwards, the LT1965 behaves as if a diode is in series with its input. No reverse current flows into the LT1965 and no reverse voltage appears at the load. The device protects itself and the load.
Exposed Pad (Pin 9/9, DFN and MSOP Packages Only): Ground. Tie this pin directly to Pins 4 and 5 and the PCB ground. This pin provides enhanced thermal performance with its connection to the PCB ground. See the Applications Information section for thermal considerations and calculating junction temperature.

## APPLICATIONS InFORMATION

The LT1965 series are 1.1A low dropout regulators with shutdown. The devices are capable of supplying 1.1A at a typical dropout voltage of 310 mV . The low operating quiescent current ( $500 \mu \mathrm{~A}$ for the adjustable version, $600 \mu \mathrm{~A}$ for the fixed voltage versions) drops to less than $1 \mu \mathrm{~A}$ in shutdown. In addition to the low quiescent current, the LT1965 regulators incorporate several protection features that makes them ideal for use in battery-powered systems. The devices protect themselves against both reverse input and reverse outputvoltages. In battery backup applications, if a backup battery holds up the output when the input is pulled to ground, the LT1965 performs like it has a diode in series with its output, preventing reverse current flow. Also, in dual supply applications where the regulator load is returned to a negative supply, the output can be pulled below ground by as much as 20V. The LT1965 still starts and operates normally in this situation.

## Adjustable Operation

The LT1965 adjustable version has an output voltage range of 1.20 V to 19.5 V . Figure 2 illustrates that the ratio of two external resistors sets the output voltage. The device servos the output to maintain the ADJ pin voltage at 1.20 V referenced to ground. R1's current equals 1.20V/R1. R2's current equals R1's current plus the ADJ pin bias current. The ADJ pin bias current, $1.3 \mu \mathrm{~A}$ at $25^{\circ} \mathrm{C}$, flows through R2 into the ADJ pin. Use the formula in Figure 2 to calculate output voltage. Linear Technology recommends that R1's value be less than 12.1 k to minimize output voltage errors due to the ADJ pin bias current. In shutdown, the output turns off and the divider current is zero. For curves depicting ADJ Pin Voltage vs Temperature and ADJ Pin Bias Current vs Temperature, see the Typical Performance Characteristics section.


Figure 2. Adjustable Operation

The adjustable device is tested and specified with the ADJ pin tied to the OUT pin for an output voltage of 1.20 V . Specifications for output voltages greater than 1.20 V are proportional to the ratio of the desired output voltage to 1.20 V : $\mathrm{V}_{\text {OUT }} / 1.20 \mathrm{~V}$. For example, Ioad regulation for an output current change of 1 mA to 1.1 A is typically -4.25 mV at $\mathrm{V}_{\text {OUT }}=1.20 \mathrm{~V}$. At $\mathrm{V}_{\text {OUT }}=5 \mathrm{~V}$, load regulation is:

$$
\frac{5 \mathrm{~V}}{1.20 \mathrm{~V}} \cdot-4.25 \mathrm{mV}=-17.71 \mathrm{mV}
$$

## Output Capacitance

The LT1965's design is stable with a wide range of output capacitors. The ESR of the output capacitor affects stability, most notably with small capacitors. A minimum output capacitor of $10 \mu \mathrm{~F}$ with an ESR of $3 \Omega$ or less is recommended to prevent oscillations. The LT1965 is a low quiescent current device and output load transient response is a function of output capacitance. Larger values of output capacitance decrease the peak deviations and provide improved transient response for larger current changes.

Ceramic capacitors require extra consideration. Manufacturers make ceramic capacitors with a variety of dielectrics, each with different behavior across temperature and applied voltage. The most common dielectrics used are specified with EIA temperature characteristic codes of Z5U, Y5V, X5R and X7R. The Z5U and Y5V dielectrics provide high C-V products in a small package at low cost, but exhibit strong voltage and temperature coefficients as shown in Figures 3 and 4 . When used with a 5 V regulator, a 16 V $10 \mu \mathrm{~F}$ Y5V capacitor can exhibit an effective value as low as $1 \mu \mathrm{~F}$ to $2 \mu \mathrm{~F}$ for the DC bias applied and over the operating temperature range. The X5R and X7R dielectrics yield much more stable characteristics and are more suitable for use as the output capacitor. The X7R type works over a wider temperature range and has better temperature stability whereas X 5 R is less expensive and is available in higher values. Care still must be exercised when using X5R and X7R capacitors; the X5R and X7R codes only specify operating temperature range and maximum capacitance change over temperature. Capacitance change due to DC bias with X5R and X7R capacitors is better than Y5V and Z5U capacitors, but can still be significant enough to drop

## LT1965 Series

## APPLICATIONS INFORMATION

capacitor values below appropriate levels. Capacitor DC bias characteristics tend to improve as component case size increases, but expected capacitance at operating voltages should be verified.

Voltage and temperature coefficients are not the only sources of problems. Some ceramic capacitors have a piezoelectric response. A piezoelectric device generates voltage across its terminals due to mechanical stress, similar to the way a piezoelectric accelerometer or microphone works. For a ceramic capacitor, the stress can be induced by vibrations in the system or thermal transients. The resulting voltages produced can cause appreciable amounts of noise. A ceramic capacitor produced the trace in Figure 5 in response to light tapping from a pencil. Similar vibration induced behavior can masquerade as increased output voltage noise.

Figure 3. Ceramic Capacitor DC Bias Characteristics

## Overload Recovery

Like many IC power regulators, the LT1965 has safe operating area protection. The safe area protection decreases currentlimit as input-to-outputvoltage increases and keeps the power transistor inside a safe operating region for all values of input-to-output voltage. The protective design provides some output current at all values of input-tooutput voltage up to the device breakdown.

When power is first applied, as input voltage rises, the output follows the input, allowing the regulator to start up into very heavy loads. During start-up, as the input voltage is rising, the input-to-output voltage differential is small, allowing the regulator to supply large output currents. With a high input voltage, a problem can occur wherein removal of an output short will not allow the output to


Figure 4. Ceramic Capacitor Temperature Characteristics


Figure 5. Noise Resulting from Tapping on a Ceramic Capacitor

## APPLICATIONS INFORMATION

recover. Other regulators, such as the LT1083/LT1084/ LT1085 family, also exhibit this phenomenon, so it is not unique to the LT1965.

The problem occurs with a heavy output load when the input voltage is high and the output voltage is low. Common situations occur immediately after the removal of a short-circuit or if the shutdown pin is pulled high after the input voltage has already been turned on. The load line for such a load may intersect the output current curve at two points. Ifthis happens, there are two stable output operating points for the regulator. With this double intersection, the input power supply may need to be cycled down to zero and brought up again to make the output recover.

## Output Voltage Noise

The LT1965 regulators are designed to provide low output voltage noise over the 10 Hz to 100 kHz bandwidth while operating at full load. Outputvoltage noise is approximately $80 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ over this frequency bandwidth for the LT1965 adjustable version. For higher output voltages (generated by using a resistor divider), the output voltage noise gains up accordingly.

Higher values of output voltage noise may be measured if care is not exercised with regard to circuit layout and testing. Crosstalk from nearby traces can induce unwanted noise onto the LT1965's output. Power supply ripple rejection must also be considered; the LT1965 regulators do not have unlimited power supply rejection and will pass a small portion of the input noise through to the output.

## Thermal Considerations

The LT1965's maximum rated junction temperature of $125^{\circ} \mathrm{C}$ limits its power handling capability. Two components comprise the power dissipated by the device:

1. Output current multiplied by the input/output voltage differential: $I_{\text {OUT }} \bullet\left(\mathrm{V}_{\text {IN }}-\mathrm{V}_{\text {OUT }}\right)$, and
2. GND pin current multiplied by the input voltage: $I_{G N D} \cdot V_{I N}$

GND pin current is determined using the GND Pin Current curves in the Typical Performance Characteristics section. Power dissipation equals the sum of the two components listed.

The LT1965 regulators have internal thermal limiting that protect the device during overload conditions. For continuous normal conditions, do not exceed the maximum junction temperature rating of $125^{\circ} \mathrm{C}$. Carefully consider all sources of thermal resistance from junction to ambient including other heat sources mounted in proximity to the LT1965.

The underside of the LT1965 DFN package has exposed metal $\left(4 \mathrm{~mm}^{2}\right)$ from the lead frame to the die attachment. The underside of the LT1965 MSOP package also has exposed metal $\left(3.7 \mathrm{~mm}^{2}\right)$. Both packages allow heat to directly transfer from the die junction to the printed circuit board metal to control maximum operating junction temperature. The dual-in-line pin arrangement allows metal to extend beyond the ends of the package on the topside (component side) of a PCB. Connect this metal to GND on the PCB. The multiple IN and OUT pins of the LT1965 also assist in spreading heat to the PCB.

For surface mount devices, heat sinking is accomplished by using the heat spreading capabilities of the PC board and its copper traces. Copper board stiffeners and plated through-holes can also be used to spread the heat generated by power devices.

## LT1965 Series

## APPLICATIONS INFORMATION

The following tables list thermal resistance for several different board sizes and copper areas. All measurements were taken in still air on $1 / 16^{\prime \prime}$ FR-4 board with one ounce copper.
Table 1. Measured Thermal Resistance for DFN Package

| Copper Area <br> Topside |  | Backside | Board Area |
| :---: | :---: | :---: | :---: | | Thermal Resistance |
| :---: |
| (Junction-to-Ambient) |\(~\left(\begin{array}{cccc} \& 60^{\circ} \mathrm{C} / \mathrm{W} <br>

\hline 2500 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 62^{\circ} \mathrm{C} / \mathrm{W} <br>
\hline 1000 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 65^{\circ} \mathrm{C} / \mathrm{W} <br>
\hline 225 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 68^{\circ} \mathrm{C} / \mathrm{W} <br>
\hline 100 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 70^{\circ} \mathrm{C} / \mathrm{W} <br>
\hline 50 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& 2500 \mathrm{~mm}^{2} \& <br>
\hline\end{array}\right.\)
*Device is mounted on topside
Table 2. Measured Thermal Resistance for MSOP Package

| Copper Area <br> Topside |  | Backside | Board Area |
| :---: | :---: | :---: | :---: | | Thermal Resistance |
| :---: |
| (Junction-to-Ambient) |$~$|  |  |  |
| :---: | :---: | :---: |
| $2500 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ |
| $1000 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ |
| $225 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ |
| $100 \mathrm{~mm}^{2} \mathrm{C} / \mathrm{W}$ |  |  |
| $50 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ |
|  | $2500 \mathrm{~mm}^{2}$ | $2500 \mathrm{~mm}^{2}$ |
| $5^{\circ} \mathrm{C} / \mathrm{W}$ |  |  |

*Device is mounted on topside
Table 3. Measured Thermal Resistance for DD-PAK Package

| Copper Area <br> Topside* |  | Backside | Board Area |
| :---: | :---: | :---: | :---: | | Thermal Resistance |
| :---: |
| (Junction-to-Ambient) |

*Device is mounted on topside

## Measured Thermal Resistance for T0-220 Package

Thermal Resistance (Junction-to-Case) $=3^{\circ} \mathrm{C} / \mathrm{W}$

## Calculating Junction Temperature

Example: Given an output voltage of 2.5 V , an input voltage range of $3.3 \mathrm{~V} \pm 5 \%$, an output current range of 0 mA to 500 mA and a maximum ambient temperature of $85^{\circ} \mathrm{C}$, what will the maximum junction temperature be?
The power dissipated by the device equals:

$$
\mathrm{I}_{\text {OUT }(\operatorname{MAX)}} \bullet\left(\mathrm{V}_{\text {IN(MAX })}-\mathrm{V}_{\text {OUT }}\right)+\mathrm{I}_{\operatorname{GND}} \bullet \mathrm{V}_{\operatorname{IN}(\operatorname{MAX})}
$$

where:

$$
\begin{aligned}
& I_{\text {OUT(MAX }}=500 \mathrm{~mA} \\
& \mathrm{~V}_{\text {IN(MAX }}=3.465 \mathrm{~V} \\
& \mathrm{I}_{\text {GND }} \text { at }\left(\mathrm{I}_{\text {OUT }}=500 \mathrm{~mA}, \mathrm{~V}_{\text {IN }}=3.465 \mathrm{~V}\right)=8.2 \mathrm{~mA}
\end{aligned}
$$

So,

$$
P=500 \mathrm{~mA}(3.465 \mathrm{~V}-2.5 \mathrm{~V})+8.2 \mathrm{~mA}(3.465 \mathrm{~V})=0.511 \mathrm{~W}
$$

Using a DFN package, the thermal resistance will be in the range of $60^{\circ} \mathrm{C} / \mathrm{W}$ to $70^{\circ} \mathrm{C} / \mathrm{W}$ depending on the copper area. So the junction temperature rise above ambient approximately equals:

$$
0.511 \mathrm{~W} \cdot 65^{\circ} \mathrm{C} / \mathrm{W}=33.22^{\circ} \mathrm{C}
$$

The maximum junction temperature equals the maximum ambienttemperature plus the maximum junction temperature rise above ambient or:

$$
\mathrm{T}_{\text {JMAX }}=85^{\circ} \mathrm{C}+33.22^{\circ} \mathrm{C}=118.22^{\circ} \mathrm{C}
$$

## APPLLCATIONS InFORMATION

## Protection Features

The LT1965 regulators incorporate several protection features that makes them ideal for use in battery-powered circuits. In addition to the normal protection features associated with monolithic regulators, such as current limiting and thermal limiting, the devices also protect against reverse input voltages, reverse output voltages and reverse output-to-input voltages.

Current limit protection and thermal overload protection protect the device against current overload conditions at its output. For normal operation, do not exceed the maximum rated junction temperature of $125^{\circ} \mathrm{C}$.

The input of the device withstands reverse voltages of 22 V . The LT1965 limits current flow to less than 1mA (typically less than $300 \mu \mathrm{~A}$ ) and no negative voltage appears at the output. The device protects both itself and the load against batteries that are plugged in backwards.

The LT1965 incurs no damage if its output is pulled below ground. If the input is left open circuit or grounded, the output can be pulled below ground by 22 V . For fixed voltage versions, the output will act like a large resistor, typically 5 k or higher, limiting current flow to typically less than $300 \mu \mathrm{~A}$. For the adjustable version, the output acts like an open circuit and no current flows from the output. However, current flows in (but is limited by) the resistor divider that sets the output voltage. If the input is powered by a voltage source, the output sources current equal to its current limit capability and the LT1965 protects itself by thermal limiting. In this case, grounding the SHDN pin turns off the device and stops the output from sourcing current.

The LT1965 adjustable version incurs no damage if the ADJ pin is pulled above or below ground by 9 V . If the input is left open circuit or grounded, the ADJ pin performs like an open circuit when pulled below ground and like a large resistor (typically 5k up to 3 V on the ADJ pin and then 1.5 k up to 9 V ) in series with a diode when pulled above ground.

In situations where the ADJ pin connects to a resistor divider that would pull the ADJ pin above its 9V clamp voltage if the output is pulled high, the ADJ pin input current must be limited to less than 5 mA . For example, a resistor divider is used to provide a regulated 1.5 V output from the 1.20 V reference when the output is forced to 20 V . The top resistor of the resistor divider must be chosen to limit the current into the ADJ pin to less than 5mA when the ADJ pin is at 9V. The 11 V difference between the OUT and ADJ pins divided by the 5mA maximum current into the ADJ pin yields a minimum top resistor value of 2.2 k .
In circuits where a backup battery is required, several different input/output conditions can occur. The output voltage may be held up while the input is either pulled to ground, pulled to some intermediate voltage, or is left open circuit. Current flow back into the output follows the curve shown in Figure 6.

If the LT1965's IN pin is forced below the OUT pin or the OUT pin is pulled above the IN pin, input current typically drops to less than $2 \mu \mathrm{~A}$. This occurs if the LT1965 input is connected to a discharged (low voltage) battery and either a backup battery or a second regulator holds up the output. The state of the SHDN pin has no effect on the reverse output current if the output is pulled above the input.


Figure 6. Reverse Output Current

## TYPICAL APPLICATIONS

Paralleling of Regulators for Higher Output Current


## LT1965 Series

## PACKAGE DESCRIPTION

## DD Package

8-Lead Plastic DFN ( $3 \mathrm{~mm} \times 3 \mathrm{~mm}$ )
(Reference LTC DWG \# 05-08-1698)


RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS
NOTE:

1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE MO-229 VARIATION OF (WEED-1)
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE

MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15 mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON TOP AND BOTTOM OF PACKAGE

MS8E Package
8-Lead Plastic MSOP
(Reference LTC DWG \# 05-08-1662)


NOTE:

1. DIMENSIONS IN MILLIMETER/(INCH)
2. DRAWING NOT TO SCALE
3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED $0.152 \mathrm{~mm}(.006$ ") PER SIDE

4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.

INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152 mm (.006") PER SIDE
5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102 mm (.004") MAX

## PACKAGE DESCRIPTION

## Q Package

5-Lead Plastic DD Pak
(Reference LTC DWG \# 05-08-1461)


BOTTOM VIEW OF DD PAK HATCHED AREA IS SOLDER PLATED COPPER HEAT SINK



RECOMMENDED SOLDER PAD LAYOUT


RECOMMENDED SOLDER PAD LAYOUT FOR THICKER SOLDER PASTE APPLICATIONS

## T Package

5-Lead Plastic TO-220 (Standard)
(Reference LTC DWG \# 05-08-1420)


## LT1965 Series

## TYPICAL APPLICATION



## RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
| :---: | :---: | :---: |
| LT1129 | 700mA, Micropower, LDO | $\mathrm{V}_{\text {IN: }}: 4.2 \mathrm{~V}$ to $30 \mathrm{~V}, \mathrm{~V}_{\text {OUT (MIIN) }}=3.8 \mathrm{~V}, \mathrm{~V}_{D O}=0.40 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=50 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=16 \mu \mathrm{~A}$; DD, SOT-223, S8, TO220-5 and TSSOP20 Packages |
| LT1761 | 100mA, Low Noise Micropower, LDO | $\mathrm{V}_{\text {IN }}: 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN })}=1.22 \mathrm{~V}, \mathrm{~V}_{\text {DO }}=0.30 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=20 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise $<20 \mu V_{\text {RMS }}$, Stable with $1 \mu \mathrm{~F}$ Ceramic Capacitors, ThinSOT™ Package |
| LT1762 | 150mA, Low Noise Micropower, LDO | $\mathrm{V}_{\text {IN: }} 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN }}=1.22 \mathrm{~V}, \mathrm{~V}_{\text {DO }}=0.30 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=25 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise < $20 \mu \mathrm{~V}_{\text {RMS }}$, MS8 Package |
| LT1763 | 500mA, Low Noise Micropower, LDO | $\mathrm{V}_{\text {IN: }} 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN }}=1.22 \mathrm{~V}, \mathrm{~V}_{\text {DO }}=0.30 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=30 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise < $20 \mu V_{\text {RMS }}$, S8 Package |
| LT1764/ <br> LT1764A | 3A, Low Noise, Fast Transient Response, LDO | $\mathrm{V}_{\text {IN: }}: 2.7 \mathrm{~V}$ to 20V, $\mathrm{V}_{\text {OUT(MIN) }}=1.21 \mathrm{~V}, \mathrm{~V}_{\mathrm{DO}}=0.34 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise $<40 \mu V_{\text {RMS }}$, "A" Version Stable with Ceramic Capacitors, DD and T0220-5 Packages |
| LTC1844 | 150mA, Very Low Drop-Out LDO | $\mathrm{V}_{\text {IN: }}: 1.6 \mathrm{~V}$ to $6.5 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN })}=1.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{DO}}=0.08 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=35 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise $<60 \mu V_{\text {RMS }}$, ThinSOT ${ }^{\text {TM }}$ Package |
| LT1962 | 300mA, Low Noise Micropower, LDO | $\mathrm{V}_{\text {IN: }} 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN }}=1.22 \mathrm{~V}, \mathrm{~V}_{\text {DO }}=0.27 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=30 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise < $20 \mu \mathrm{~V}_{\text {RMS }}$, MS8 Package |
| LT1963/ LT1963A | 1.5A, Low Noise, Fast Transient Response, LDO | $\mathrm{V}_{\text {IN: }}$ : 2.1 V to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN })}=1.21 \mathrm{~V}, \mathrm{~V}_{\mathrm{DO}}=0.34 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise < $40 \mu V_{\text {RMS }}$, "A" Version Stable with Ceramic Capacitors; DD, T0220-5, SOT-223 and S8 Packages |
| LT3020 | 100 mA , Low Voltage $\mathrm{V}_{\mathrm{DO}}, \mathrm{V}_{\mathrm{IN}(\mathrm{MIN})}=0.9 \mathrm{~V}$, LDO | $\mathrm{V}_{\text {IN: }}: 0.9 \mathrm{~V}$ to $10 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN })}=0.20 \mathrm{~V}, \mathrm{~V}_{\mathrm{DO}}=0.15 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=120 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=3 \mu \mathrm{~A}, \mathrm{DFN}$ and MS8 Packages |
| LT3021 | 500 mA , Low Voltage $\mathrm{V}_{\mathrm{DO}}, \mathrm{V}_{\mathrm{IN}(\mathrm{MIN})}=0.9 \mathrm{~V}$, LDO | $\mathrm{V}_{\text {IN: }}: 0.9 \mathrm{~V}$ to $10 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN) }}=0.20 \mathrm{~V}, \mathrm{~V}_{\text {DO }}=0.16 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=120 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=3 \mu \mathrm{~A}, \mathrm{DFN}$ and S8 Packages |
| LT3023 | Dual, $2 x$ 100mA, Low Noise Micropower, LDO | $\mathrm{V}_{\text {IN: }}: 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN })}=1.22 \mathrm{~V}, \mathrm{~V}_{\mathrm{DO}}=0.30 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=40 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}, \mathrm{DFN}$ and MS10 Packages |
| LT3024 | Dual, $100 \mathrm{~mA} / 500 \mathrm{~mA}$, Low Noise Micropower, LDO | $\mathrm{V}_{\text {IN: }}: 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN })}=1.22 \mathrm{~V}, \mathrm{~V}_{\mathrm{DO}}=0.30 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=60 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}, \mathrm{DFN}$ and TSSOP Packages |
| LT3027 | Dual, $2 \times 100 \mathrm{~mA}$, Low Noise Micropower, LDO with Independent Inputs | $\mathrm{V}_{\text {IN: }}: 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN }}=1.22 \mathrm{~V}, \mathrm{~V}_{\text {DO }}=0.30 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=25 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise $<20 \mu V_{\text {RMS }}$, DFN and MS10 Packages |
| LT3028 | Dual, $100 \mathrm{~mA} / 500 \mathrm{~mA}$, Low Noise Micropower, LDO with Independent Inputs | $\mathrm{V}_{\text {IN: }}: 1.8 \mathrm{~V}$ to $20 \mathrm{~V}, \mathrm{~V}_{\text {OUT(MIN) }}=1.22 \mathrm{~V}, \mathrm{~V}_{\text {DO }}=0.30 \mathrm{~V}, \mathrm{I}_{\mathrm{Q}}=30 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{SD}}=<1 \mu \mathrm{~A}$, Low Noise < $20 \mu V_{\text {RMS }}$, DFN and TSSOP Packages |
| $\begin{aligned} & \text { LT3080/ } \\ & \text { LT3080-1 } \end{aligned}$ | 1.1A Parallelable, Low Noise, Low Dropout Linear Regulator | 300 mV Dropout Voltage (2-Supply Operation), Low Noise: $40 \mu \mathrm{~V}_{\text {RMS }}$, VIN : 1.2 V to 36 V , $\mathrm{V}_{\text {OUT }}$ : OV to 35.7V, Current-Based Reference with 1-Resistor Vout Set; Directly Parallelable (No Op Amp Required), Stable with Ceramic Caps, T0-220, SOT-223, MSOP and $3 \mathrm{~mm} \times 3 \mathrm{~mm}$ DFN Packages; LT3080-1 Version Has Integrated Internal Ballast Resistor |

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